

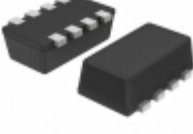

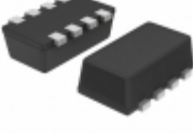
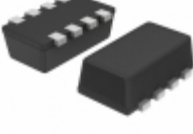

	<h2 style="color: red;">NTHD2102PT1</h2>
	<p><b>Hersteller-Teilenummer:</b> NTHD2102PT1</p> <p><b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET 2P-CH 8V 3.4A CHIPFET</p> <p><b>Datenblätter:</b>  <a href="#">NTHD2102PT1.pdf</a></p> <p><b>RoHs Status:</b> Enthält Blei / RoHS nicht konform</p> <p><b>Lagerzustand:</b> New original, 22960 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	NTHD2102PT1
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2P-CH 8V 3.4A CHIPFET
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	22960 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.1W
Verpackung / Gehäuse	8-SMD, Flat Lead
Supplier Device-Gehäuse	ChipFET™
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.4A
Rds On (Max) @ Id, Vgs	58 mOhm @ 3.4A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 2.5V
Eingabekapazität (Ciss) (Max) @ Vds	715pF @ 6.4V
Verpackung	Tape & Reel (TR)



































NTHD2102PT1 ist neu im Original, Suche NTHD2102PT1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTHD2102PT1 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTHD2102PT1: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>NTHC5513T1</b> AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>	 <p><b>NTHA3HB-1.5440-E(T)</b> PERICOM PERICOM SMD</p>	 <p><b>NTHD3100CT3</b> AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>	 <p><b>NTHD3100CT1G</b> AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V CHIPFET</p>
 <p><b>NTHD2110TT1G</b> AMI Semiconductor / ON Semiconductor MOSFET P-CH 12V 4.5A CHIPFET</p>	 <p><b>NTHC5513T1G</b> AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V 1206A</p>	 <p><b>NTHA8HC-60.000</b> N/A NTHA8HC-60.000 N/A</p>	 <p><b>NTHA3HC-2.048-E</b> PERICOM PERICOM SMD</p>

### heiße Teile

Mehr

 NTH05HC-32.768	 NTH08HB3-30.000	 NTHA8HC-60.000	 NTHC5513T1	 NTHC5513T1G
 NTHD2102PT1G	 NTHD3100CT1	 NTHD3101FT1	 NTHD3101FT1G	 NTHD3102CT1G
 NTHD310FT1G	 NTHD3133PFT1G	 NTHD4102PT1	 NTHD4102PT1G	 NTHD4401PT1G
 NTHD4401PT3G	 NTHD4502NT1	 NTHD4502NT1G	 NTHD4508NT1	 NTHD4508NT1G
 NTHD4N02FT1	 NTHD4N02FT1G	 NTHD4P02FT1	 NTHD4P02FT1-D	 NTHD4P02FT1G
 NTHD5902	 NTHD5902T1	 NTHD5903T1	 NTHD5903T1G	 NTHD5904N
 NTHD5904NT1	 NTHD5904NT1G	 NTHD5905T1	 NTHD5905T1G	 NTHS0402N02N1002HE
 NTHS0603N01N1003JE	 NTHS0603N02N6801	 NTHS0603N02N6801JE	 NTHS0805N01N5002JE	 NTHS1206N01N4702JE
 NTHS1206N02N1002JR	 NTHS1206N02N1002KR	 NTHS2101PT1	 NTHS2101PT1G	 NTHS4101PT1
 NTHS4101PT1G	 NTHS4111PT1	 NTHS4166NT1G	 NTHS4501NT1	 NTHS4501NT1G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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